NSN 5962-01-371-2706

Memory Microcircuit - Page 1 of 1



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Body Width:
Between 0.290 inches and 0.320 inches
Body Height:
0.200 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and w/disable and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Sram
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
5.00 input picofarads and 7.00 output picofarads
Time Rating Per Chacteristic:
45.00 nanoseconds access
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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